

2A TRENCH SCHOTTKY BARRIER RECTIFIER CHIP-SCALE PACKAGE

Features and Benefits

Improves Efficiency

Product Summary

VRRM (V)	lo (A)	V _F Max (V)	I _R Max (μA)
60	2.0	0.58	100

Description and Applications

The SDT2U60CP3 is a 60-volt 2A trench Schottky barrier rectifier that is optimized for low-forward voltage drop and low-leakage current, housed in a compact chip-scale package (CSP) that occupies only 0.84mm² board space with low profile. The low thermal resistance enables designers to meet design challenges of increasing efficiency whilst at the same time reducing board space. The SDT2U60CP3 are ideally suited for use in portable applications as:

- Blocking diodes
- Boost diodes
- Switching diodes
- · Reverse protection diodes

Temperature Operation Totally Lead-Free & Fu

Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

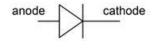
Low-Forward Voltage (VF) Minimizes Conduction Losses and

Reduced High-Temperature Reverse Leakage; Increased Reliability Against Thermal Runaway Failure in High-

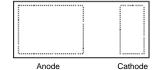
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

Mechanical Data

- Package: X3-DSN1406-2
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: NiAu Bump. Solderable per MIL-STD-202, Method 208 (e4)
- Polarity: Cathode Dot
- Weight: 0.001 grams (Approximate)



Device Schematic



Ordering Information (Note 4)

- 1						
	Part Number	Paakaga	Packing			
	Fait Number	Package	Qty.	Carrier		
	SDT2U60CP3-7	X3-DSN1406-2	5000	Tape & Reel		

Notes:

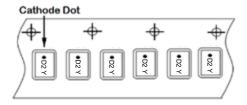
- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Pin 1



D2 = Product Type Marking Code Y = Date Code Marking Y or \overline{Y} = Year (ex: K = 2023) Dot Denotes Cathode Pin



Date Code Key

Year	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032	2033	2034
Code	K	L	М	N	Р	R	S	T	U	V	W	Х



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	Value	Unit
Peak Repetitive Reverse Voltage	V_{RRM}	60	V
Average Rectified Output Current	lo	2.0	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine Wave Superimposed on Rated Load	IFSM	18	Α
ESD (Human Body Model) ESD (Machine Model)	ESD	8 0.4	kV

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	R _{θJA}	165	°C/W
Typical Thermal Resistance Junction to Ambient (Note 6)	R _{θJA}	60	°C/W
Typical Thermal Resistance Junction to Case (Note 5)	R _{θJC}	20	°C/W
Typical Thermal Resistance Junction to Case (Note 6)	R _{θJC}	7	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

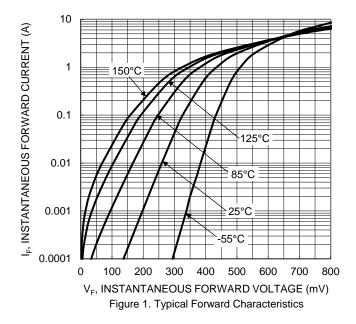
Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

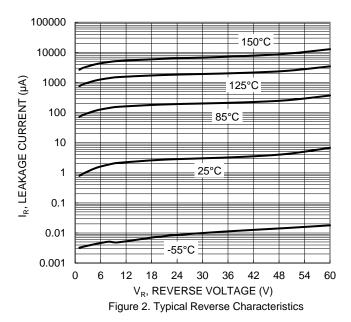
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Famuerd Voltage Dran	\/-	_	0.51	0.58	\/	IF = 2.0A, T _J = +25°C
Forward Voltage Drop	VF	_	0.45	_	V	IF = 2.0A, T _J = +125°C
Reverse Current (Note 7)	I _R	_	7	100	μA	V _R = 60V, T _J = +25°C
Junction Capacitance	Ст	_	110	_	pF	V _R = 10V, f = 1.0MHz

Notes:

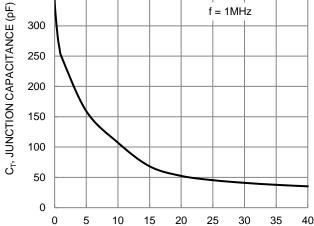
- 5. Device mounted on FR-4 PCB, 2oz copper, minimum recommended pad layout per http://www.diodes.com/package-outlines.html.
- Solution in the second se

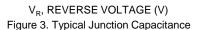


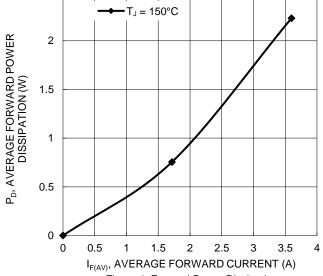




400 350 300 f = 1MHz 2.5 T_J = 150°C





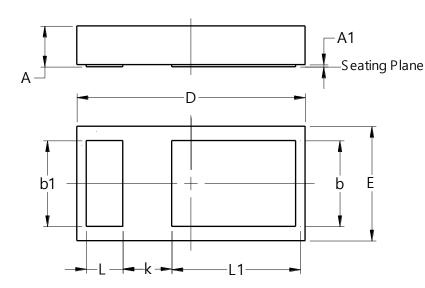




Package Outline Dimensions (Note 8)

Please see http://www.diodes.com/package-outlines.html for the latest version.

X3-DSN1406-2



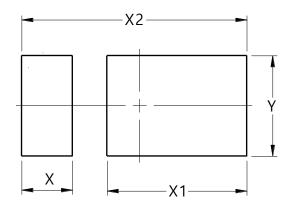
X3-DSN1406-2						
Dim	Min	Max	Тур			
Α	0.225	0.275	0.250			
A1		0.02				
b	0.495	0.535	0.510			
b1	0.495	0.535	0.510			
D	1.36	1.44	1.40			
Е	0.56	0.64	0.60			
k			0.30			
L	0.204	0.244	0.224			
L1	0.740	0.780	0.760			
All Dimensions in mm						

Note 8: Device side walls are electrically active bare silicon. Avoid contact of solder or flux on the side walls during the PCB assembly process.

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

X3-DSN1406-2



Dimensions	Value		
Dimensions	(in mm)		
Х	0.304		
X1	0.840		
X2	1.352		
Υ	0.580		



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